



Package: QFN, 4mm x 4mm



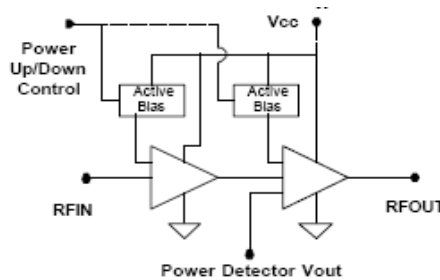
### Product Description

RFMD's SZA-2044 is a high efficiency class AB heterojunction bipolar transistor (HBT) amplifier housed in a low-cost surface-mountable plastic package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability. This product is specifically designed as a final stage 802.11b/g and 802.16 equipment in the 2.0GHz to 2.7GHz bands. It can run from a 3V to 5V supply. Optimized on-chip impedance matching circuitry provides a 50Ω nominal RF input impedance. The external output match and bias adjustability allows load line optimization for other applications over narrower bands. It features an output power detector, on/off power control, and high RF overdrive robustness. This product is available in a ROHS Compliant and Green package with matte tin finish, designated by the "Z" package suffix.

#### Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- RF MEMS

### Functional Block Diagram



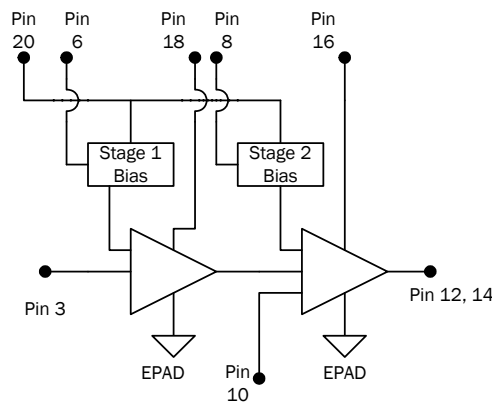
### Features

- Z Part Number is Available in RoHS Compliant, Pb-Free, and RFMD Green
- 802.11g 54Mb/s Class AB Performance
- P<sub>OUT</sub> = 22dBm at 3% EVM, 5V, 340mA
- P<sub>OUT</sub> = 18dBm at 3% EVM, 3.3V, 175mA
- On-Chip Output Power Detector
- P<sub>1dB</sub> = 29.5dBm at 5V, P<sub>1dB</sub> = 25dBm at 3.3V
- Robust - Survives RF Input Power = +15dBm
- Power Up/Down Control <1μs
- Available in RoHS Green Compliant Package

### Applications

- 802.11b/g WiFi, 2.4GHz ISM Applications

### Simplified Device Schematic



## Absolute Maximum Ratings

| Parameter                                    | Rating      | Unit |
|--|-------------|------|
| VC2 Collector Bias Current ( $I_{VC2}$ )     | 500         | mA   |
| VC1 Collector Bias Current ( $I_{VC1}$ )     | 150         | mA   |
| Device Voltage ( $V_D$ ), No RF drive        | 7.0         | V    |
| Power Dissipation                            | 3           | W    |
| Operating Ambient Temperature ( $T_A$ )      | -40 to +85  | °C   |
| Max RF Input Power for 50Ω output load       | 15          | dBm  |
| Max RF Input power for 10:1 VSWR RF out load | 8           | dBm  |
| Storage Temperature Range                    | -40 to +150 | °C   |
| Operating Junction Temperature ( $T_J$ )     | +150        | °C   |
| ESD Rating - Human Body Model Class 1C (HBM) | 500         | V    |
| Moisture Sensitivity Level                   | MSL-1       |      |



### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table above. Bias Conditions should also satisfy the following expression:  
 $I_D V_D < (T_J - T_L) / R_{TH, j-i}$

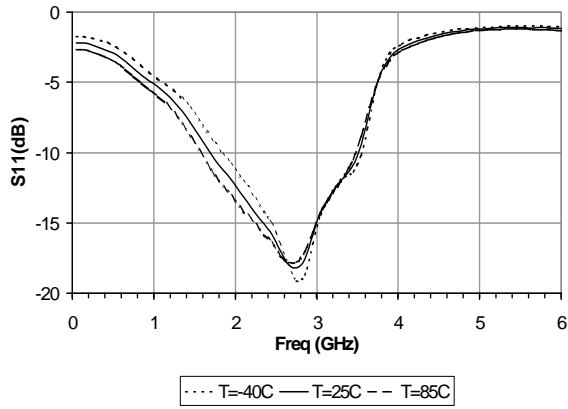
## Nominal Operating Parameters

| Parameter                       | Specification |            |       | Unit | Condition  |
|---------------------------------|---------------|------------|-------|------|--|
|                                 | Min.          | Typ.       | Max.  |      |  |
| Frequency of Operation          | 700           |            | 2700  | MHz  |  |
| Output Power at 1dB Compression |               | 28.5       |       | dBm  | 1.5GHz   |
|                                 |               | 29.5       |       | dBm  | 1.8GHz   |
|                                 |               | 29         |       | dBm  | 2.1GHz   |
|                                 |               | 29.5       |       | dBm  | 2.4GHz   |
|                                 | 28.0          | 29.5       |       | dBm  | 2.5GHz   |
| Small Signal Gain               |               | 29         |       | dB   | 1.5GHz   |
|                                 |               | 28.5       |       | dB   | 1.8GHz   |
|                                 |               | 28         |       | dB   | 2.1GHz   |
|                                 | 23.5          | 25.5       | 27.5  | dB   | 2.4GHz   |
|                                 | 23.5          | 25.5       | 27.5  | dB   | 2.5GHz   |
| Output power                    |               | 22         |       | dBm  | 2.4GHz, 3% EVM 802.11g 54Mb/s                          |
|                                 |               | 22         |       | dBm  | 2.5GHz   |
| Noise Figure                    |               | 6.1        |       | dB   | 2.5GHz   |
| Third Order Intermod            |               | -46        |       | dBc  | 1.5GHz, $P_{OUT} = 18dBm$ per tone                     |
|                                 |               | -45.5      |       | dBc  | 1.8GHz, $P_{OUT} = 18dBm$ per tone                     |
|                                 |               | -43.5      |       | dBc  | 2.1GHz, $P_{OUT} = 18dBm$ per tone                     |
|                                 |               | -44.0      | -40.0 | dBc  | 2.5GHz, 18dBm per tone, 3% EVM with IEEE802.11g 54Mbps |
| Output IP3                      |               | 41         |       | dBm  | 1.5GHz, $V_{CC} = 5V$                                  |
|                                 |               | 40.5       |       | dBm  | 1.8GHz, $V_{CC} = 5V$                                  |
|                                 |               | 39.5       |       | dBm  | 2.1GHz, $V_{CC} = 5V$                                  |
|                                 |               | 41         |       | dBm  | 2.5GHz, $V_{CC} = 5V$                                  |
| Worst Case Input Return Loss    | 10.0          | 13.0       |       | dB   | 2.4GHz to 2.5GHz                                       |
| Worst Case Output Return Loss   | 9.0           | 11.0       |       | dB   | 2.4GHz to 2.5GHz                                       |
| Output Voltage Range            |               | 0.9 to 1.7 |       | V    | $P_{OUT} = 15dBm$ to 29dBm                             |
| Quiescent Current               | 255           | 300        | 345   | mA   | $V_{CC} = 5V$  |
| Power Up Control Current        |               | 1.9        |       | mA   | $V_{PC} = 5V, (I_{VPC1} + I_{VPC2})$                   |
| Off $V_{CC}$ Leakage Current    |               | 6.0        | 100.0 | uA   | $V_{PC} = 0V$  |
| Thermal Resistance              |               | 28         |       | °C/W | junction - lead  |

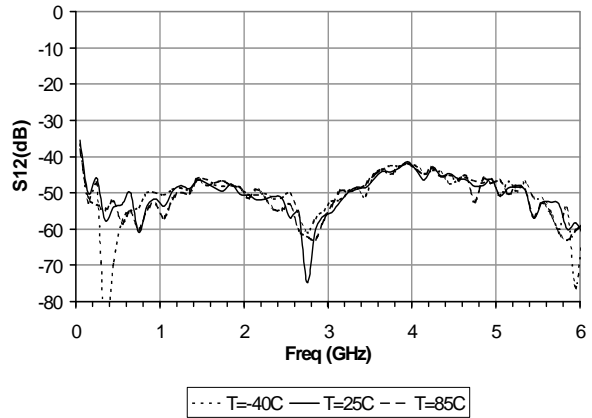
Test Conditions:  $Z_0 = 50\Omega, V_{CC} = 5V, I_Q = 300mA, T_{BP} = 30^\circ C$

Performance: 2.3GHz to 2.7GHz Evaluation Board Data ( $V_{CC} = V_{PC} = 5.0V$ ,  $I_Q = 300mA$ )

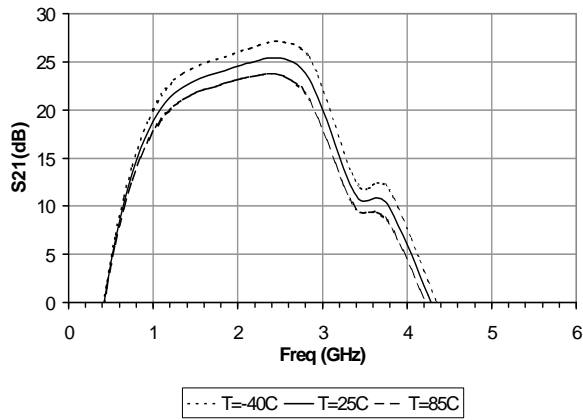
**S11 - Input Return Loss**



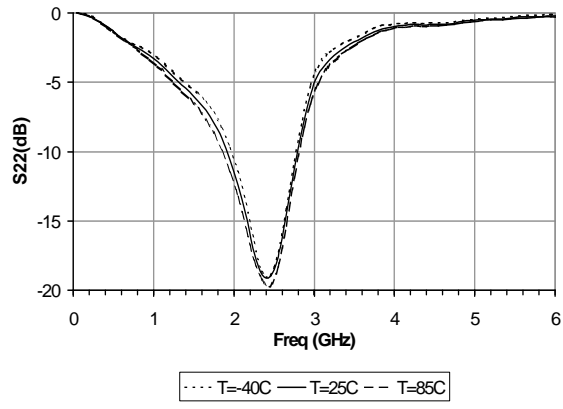
**S12 - Isolation**



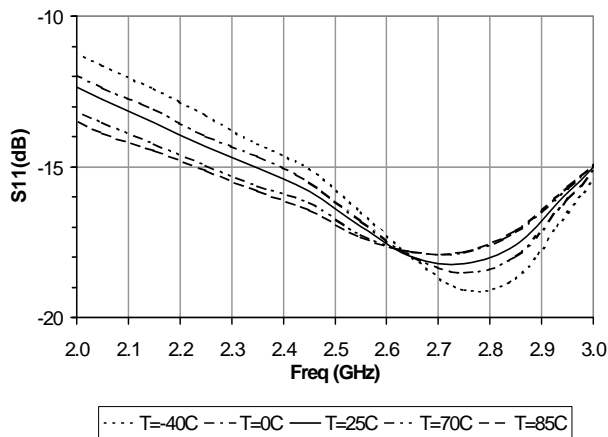
**S21 - Gain**



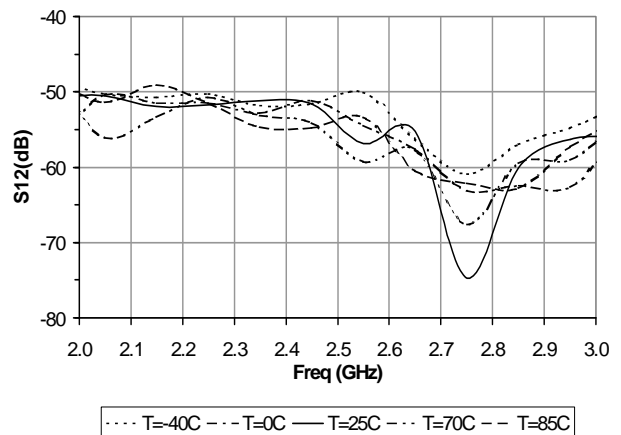
**S22 - Output Return Loss**



**Narrowband S11 - Input Return Loss**

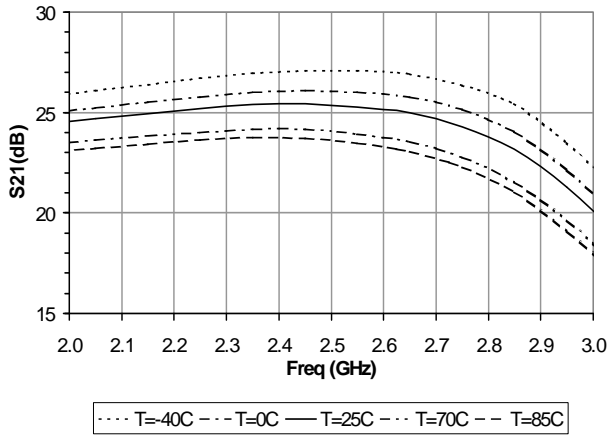


**Narrowband S12 - Isolation**

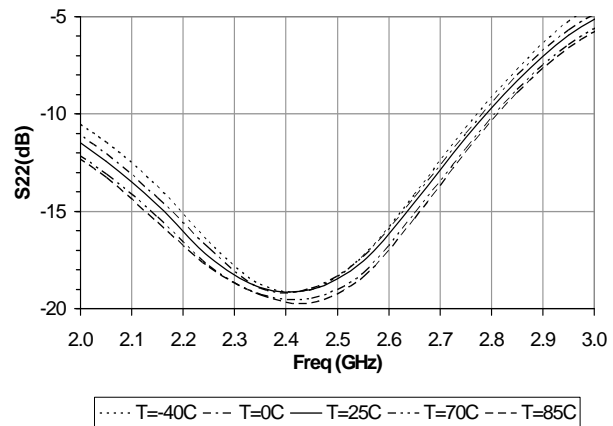


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ( $V_{CC} = V_{PC} = 5.0V$ ,  $I_Q = 300mA$ )

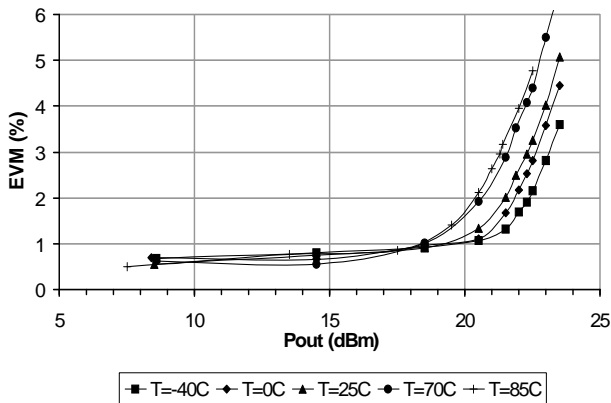
**Narrowband S21 - Gain**



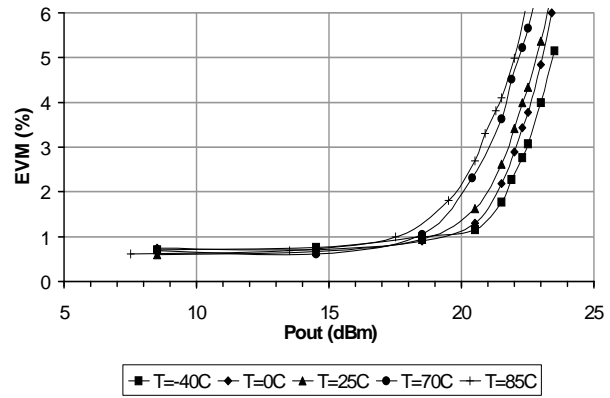
**Narrowband S22 - Output Return Loss**



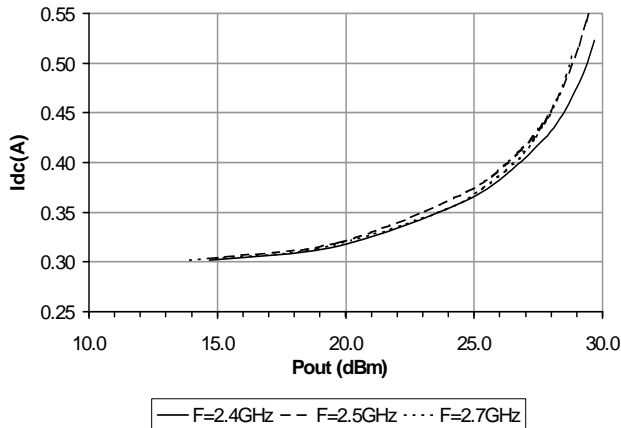
**EVM vs Pout, F=2.4GHz**  
802.11g, OFDM, 54 Mb/s, 64QAM



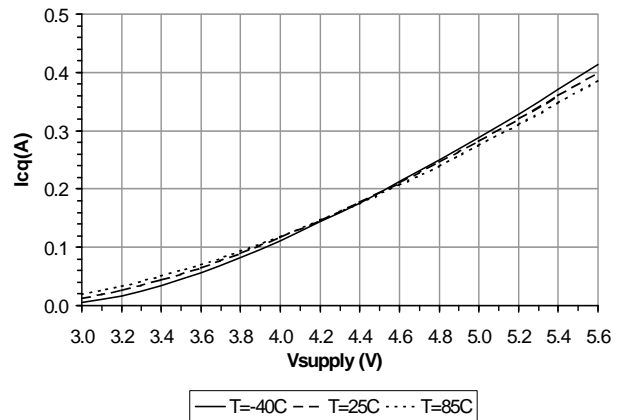
**EVM vs Pout, F=2.5GHz**  
802.11g, OFDM, 54 Mb/s, 64QAM



**DC Supply Current (Idc) vs Pout, T=25C**

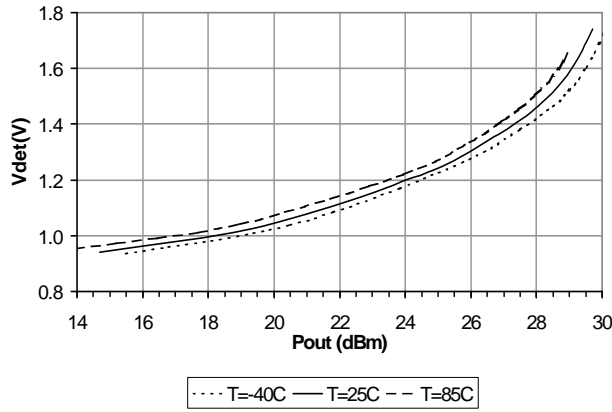


**Icq (DC Bias Point) vs Vsupply (V+ and Vpc)**

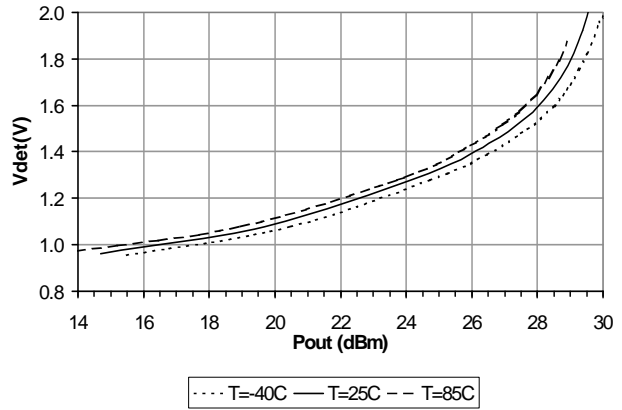


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ( $V_{CC} = V_{PC} = 5.0V$ ,  $I_Q = 300mA$ )

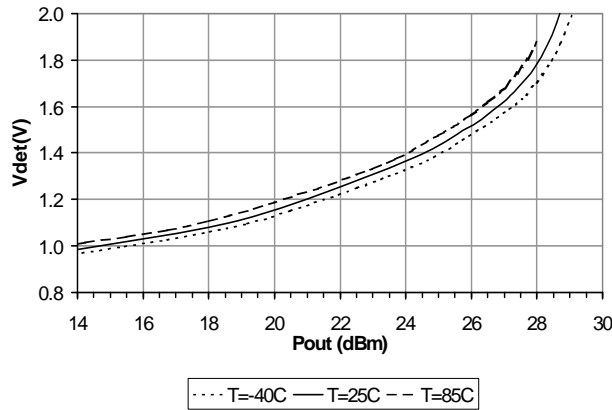
**RF Power Detector (Vdet) vs Pout  
F=2.4GHz**



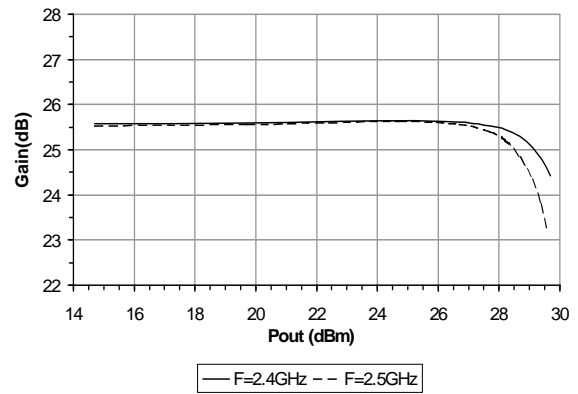
**RF Power Detector (Vdet) vs Pout  
F=2.5GHz**



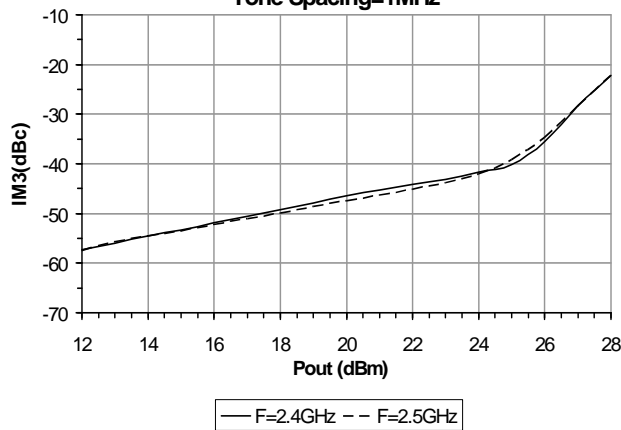
**RF Power Detector (Vdet) vs Pout  
F=2.7GHz**



**Gain vs Pout, T=25C**

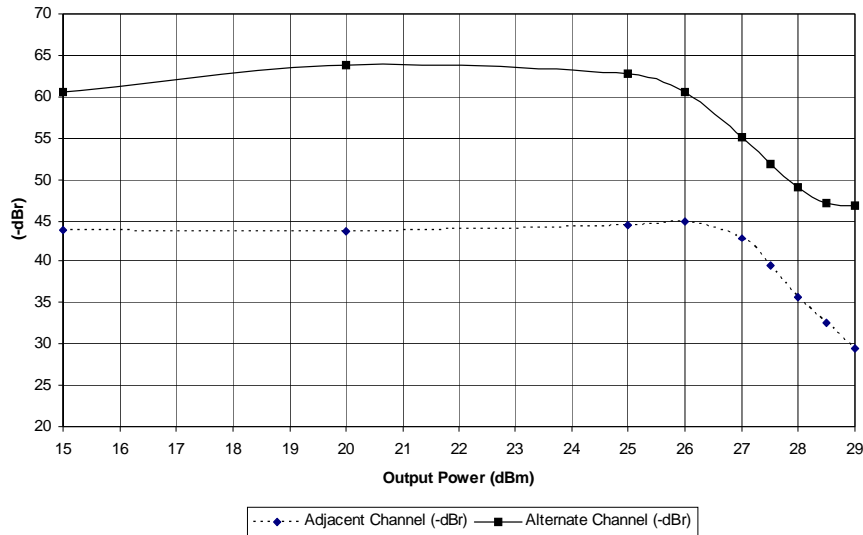


**IM3 vs Pout (2 tone avg.), T=25C  
Tone Spacing=1MHz**

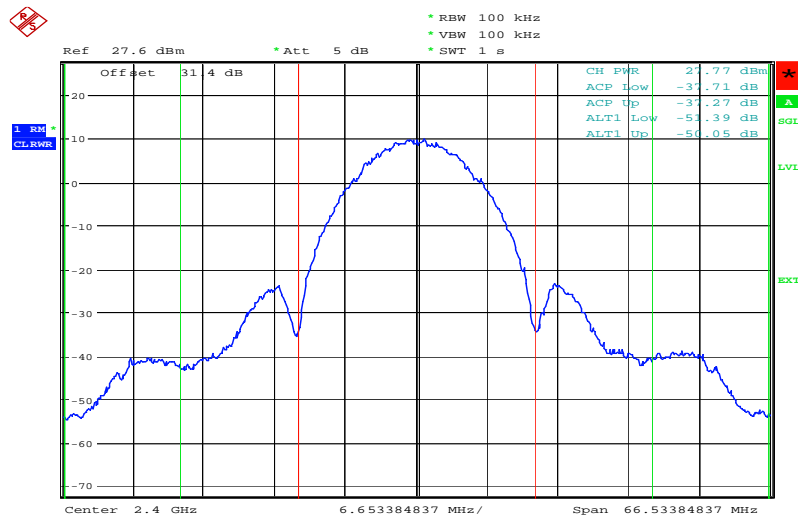


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ( $V_{CC} = V_{PC} = 5.0V$ ,  $I_Q = 300mA$ )

802.11b Spectral Regrowth vs. Output Power at 2.4 GHz



Output Power Spectrum 802.11b 11Mbps cck, Pout = 27.8dBm at 2.4GHz



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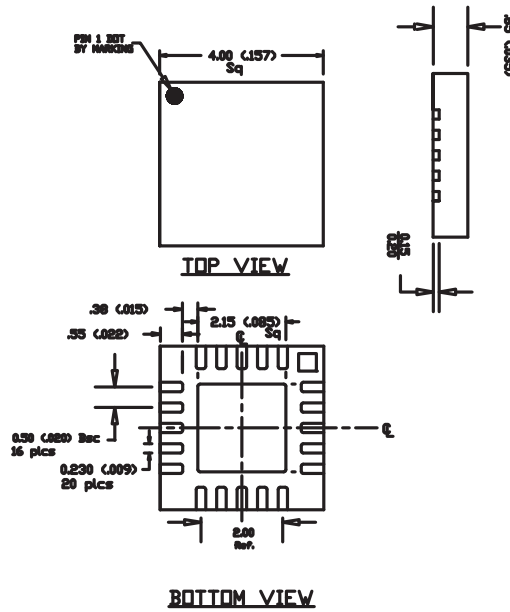
**Pin Names and Descriptions**

| Pin   | Name          | Description   |
|---|---------------|---|
| <b>1, 2,<br/>4, 5,<br/>7, 9,<br/>11,<br/>13,<br/>15,<br/>17, 19</b> | <b>N/C</b>    | These are unused pins and not wired inside the package. They may be grounded or connected to adjacent pins.   |
| <b>6</b>  | <b>VPC1</b>   | VPC1 is the bias control pin for the stage 1 active bias circuit. An external series resistor is required for proper setting of bias levels. Refer to the evaluation board schematic for resistor value. To prevent potential damage, do not apply voltage to this pin that is +1V greater than voltage applied to pin 20 (Vbias) unless Vpc supply current capability is less than 10mA. |
| <b>8</b>  | <b>VPC2</b>   | VPC2 is the bias control pin for the stage 2 active bias circuit. An external series resistor is required for proper setting of bias levels. Refer to the evaluation board schematic for resistor value. To prevent potential damage, do not apply voltage to this pin that is +1V greater than voltage applied to pin 20 (Vbias) unless Vpc supply current capability is less than 10mA. |
| <b>10</b>   | <b>VDET</b>   | Output power detector voltage. Load with >10KΩ for best performance   |
| <b>3</b>  | <b>RF IN</b>  | RF input pin. This is DC grounded internal to the IC. Do not apply voltage to this pin.   |
| <b>12, 14</b>   | <b>RF OUT</b> | RF output pin. This is also another connection to the 2nd stage collector.  |
| <b>16</b>   | <b>VC2</b>    | 2nd stage collector bias pin. Apply 3.0V to 5.0V to this pin.   |
| <b>18</b>   | <b>VC1</b>    | 1st stage collector bias pin. Apply 3.0V to 5.0V to this pin.   |
| <b>20</b>   | <b>VBIAS</b>  | Active bias network VCC. Apply 3.0V to 5.0V to this pin.  |
| <b>EPAD</b>   | <b>GND</b>    | Exposed area on the bottom side of the package needs to be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern.  |

## Package Drawing

Dimensions in Millimeters (Inches)

Refer to drawing posted at [www.rfmd.com](http://www.rfmd.com) for tolerances.



- Notes:
1. Base Metal - Copper Dln 194
  2. Lead Finish
    - Basic FN - Sn/Pb Sn =90%
    - Z option - 100% Matte Sn - .01 (0.0004) thick min

SZA-2044 - 85/15 Sn/Pb plating

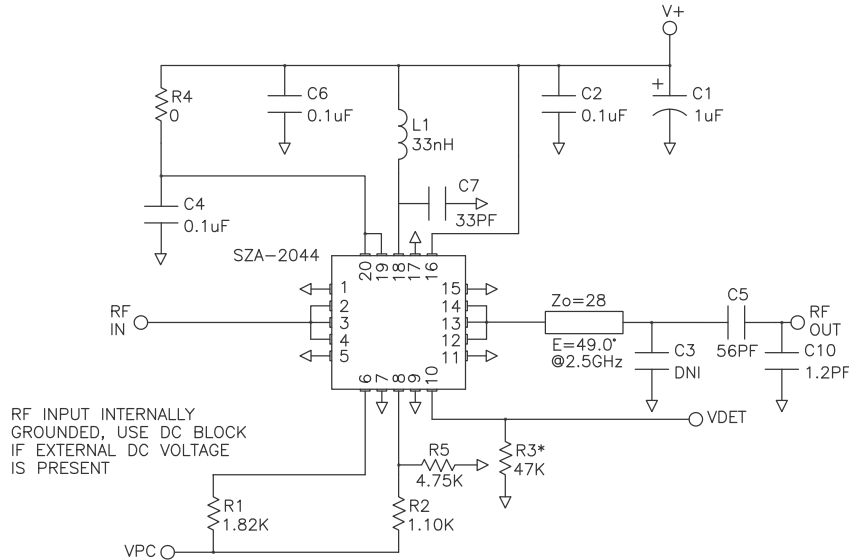
SZA-2044Z - Matte Sn plating

### Part Symbolization

The part will be symbolized with an "SZA-2044" for Sn/Pb plating or "SZA-2044Z" for RoHS green compliant product. Marking designator will be on the top surface of the package.

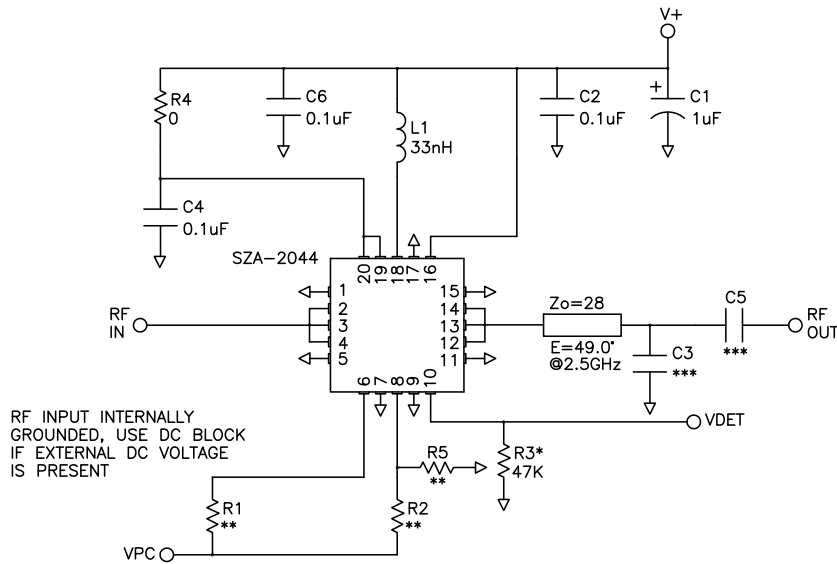


## 1.4GHz to 2.0GHz Application Schematic for $V+ = V_{CC} = 5.0$



\*R3 simulates external circuit loading to ground. Recommended load range is 10KΩ to 100KΩ. May be removed if VDET is not used

## 2.0GHz to 2.7GHz Evaluation Board Schematic For $V+ = V_{CC} = 5.0$



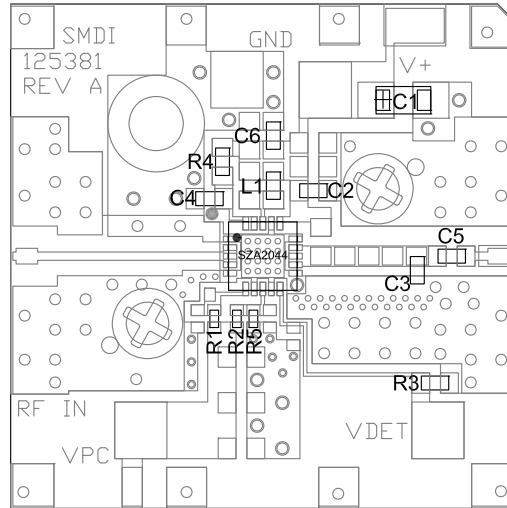
\*R3 simulates external circuit loading to ground. Recommended load range is 10kΩ to 100kΩ. May be removed if VDET is not used

\*\*See table below or application note AN-068 for values

\*\*\*See table below for matching component values

Important Note: Pins 1, 2, 4, 5, 7, 9, 11, 13, 15, 17, 19 are unwired (N/C) inside the package. Refer to page 2 for detailed pin descriptions. Some of these pins are wired to adjacent pins or grounded as shown in the application circuit. This is to maintain consistency with the evaluation board layout shown below. It is recommended to use this layout and wiring to achieve the specified performance.

## Evaluation Board Layout and Bill of Materials



| Desg | Description                                     |
|------|---|
| Q1   | SZA-2044  |
| R1   | See Table 2, 0402 1%                            |
| R2   | See Table 2, 0402 1%                            |
| R3   | 47kΩ, 0603 or 0402                              |
| R4   | 0Ω, 0603 or 0402                                |
| R5   | See Table 2, 0402 1%                            |
| C1   | 1μF 16V Tantalum Cap                            |
| C2   | 0.1μF Cap, 0603 or 0402                         |
| C3   | See Table 1, 0603                               |
| C4   | 0.1μF Cap, 0603 or 0402                         |
| C5   | See Table 1, 0603                               |
| C6   | 0.1μF Cap, 0603 or 0402                         |
| C7   | See Table 1, 0603                               |
| C10  | See Table 1, 0402                               |
| L1   | 33nH Ind, 0603<br>(Toko LL1608-FH33NJ or Equiv) |

**Table 1: Output Matching Capacitor Values**

( $V_{CC} = 5V$ ,  $I_Q = 302mA$ )

| Freq.Range       | C3    | C5   | C7   | C10   |
|------------------|-------|------|------|-------|
| 1.4GHz to 2.0GHz | DNI   | 56pF | 33pF | 1.2pF |
| 2.0GHz to 2.2GHz | 1.0pF | 15pF | DNI  | DNI   |
| 2.3GHz to 2.7GHz | 0.5pF | 15pF | DNI  | DNI   |

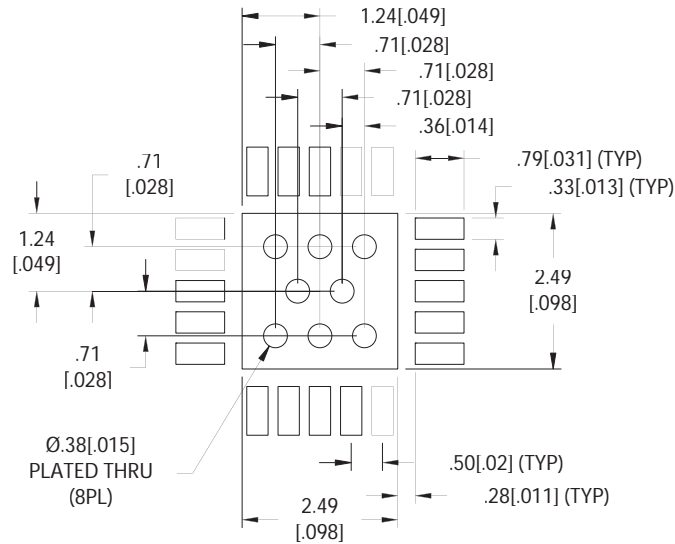
**Table 2: Resistor Values for  $V_{PC} = 2.9V$  to  $5V$**

( $V_{CC} = 5V$ ,  $I_Q = 302mA$ )

| VPC (V) | R1    | R2    | R5    |
|---------|-------|-------|-------|
| 2.9     | 34.8  | 27.4  | Out   |
| 3.0     | 121   | 105   | Out   |
| 3.1     | 205   | 182   | Out   |
| 3.2     | 287   | 261   | Out   |
| 3.3     | 374   | 332   | Out   |
| 5.0     | 1.82k | 1.10k | 4.75k |

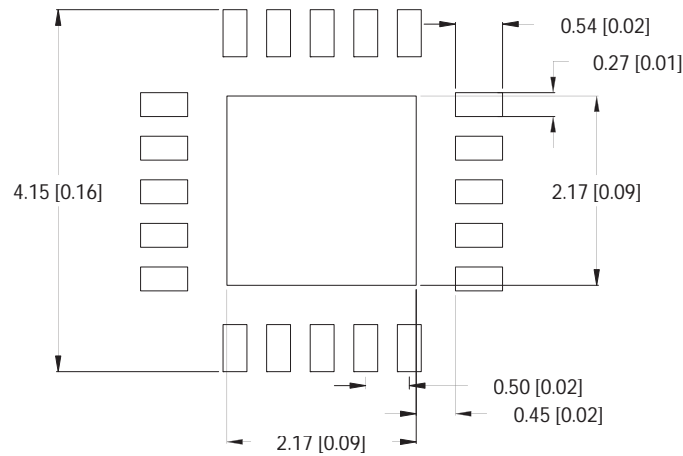
**Recommended Land Pattern**

Dimensions in millimeters (inches)



**Recommended PCB Soldermask (SMBOC) for Land Pattern**

Dimensions in millimeters (inches)



## Ordering Information

| Ordering Code    | Description  |
|------------------|--|
| SZA2044ZSQ       | Standard 25 piece bag  |
| SZA2044ZSR       | Standard 100 piece reel  |
| SZA2044Z         | Standard 1000 piece reel   |
| SZA2044ZPCK-EVB2 | Evaluation Board 2.0GHz to 2.7GHz Tune and 5 loose sample pieces |

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